NSN 5961-00-631-4999

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-631-4999 **Inclosure Material:** Metal **Overall Length:** 3.250 inches **Overall Height:** 1.000 inches **Overall Width:** 3.250 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Press fit and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 working peak reverse voltage, peak total value and 210.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 650.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No